CMOS Digital Integrated Circuits Silicon Monolithic

# TC7PCI3412MT,TC7PCI3415MT

#### 1. Functional Description

4 Differential Channel, 2:1 multiplexer/demultiplexer switch for PCI Express Gen3

#### 2. General

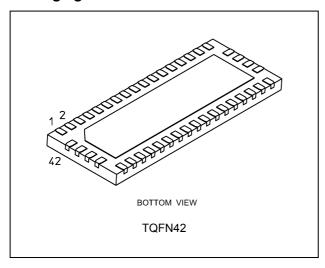
The TC7PCI3412MT and TC7PCI3415MT are 4 differential channel, 1-2 multiplexer/demultiplexer for PCI Express Gen3 (8Gbps), or other high-speed interface applications.

The An+/An- inputs is connected to the Bn+/Bn- or Cn+/Cn- outputs determined by the combination both the select input (SEL) and output enable  $(\overline{OE})$ . When the output enable  $(\overline{OE})$  input is held high-level, the switches are open (high-impedance state) with regardless the state of select inputs and reducing consumption current. All inputs are equipped with protection circuits against static discharge.

#### 3. Features

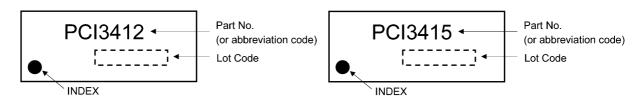
- (1) Operating voltage:  $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
- (2) Switch terminal ON-capacitance:  $C_{I/O} = 1.5 \text{ pF}$  Switch On (typ.)  $@V_{CC} = 3.3 \text{ V}$
- (3) ON resistance:  $R_{ON} = 7.5 \Omega$  (typ.) @ $V_{CC} = 3.0 \text{ V}$ ,  $V_{IS} = 0 \text{ V}$
- (4) -3dB Bandwidth: BW = 10 GHz (typ.) @  $V_{CC}$  = 3.3 V
- (5) Insertion Loss: DDIL = -1 dB (typ.) @  $V_{CC}$  = 3.3 V, f = 4 GHz
- (6) Off Isolation: DDOIRR = -20 dB (typ.) @  $V_{CC}$  = 3.3 V, f = 4 GHz
- (7) Crosstalk: DDNEXT = -40 dB (typ.) @  $V_{CC}$  = 3.3 V, f = 4 GHz
- (8) ESD performance: Machine model  $\geq \pm 200$  V, Human body model  $\geq \pm 2000$  V
- (9) Package: TQFN42

## 4. Packaging



#### 5. Marking

TC7PCl3412MT TC7PCl3415MT



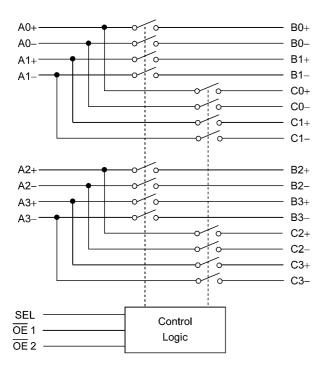


## 6. Pin Assignment

TC7PCI3412MT TC7PCI3415MT V<sub>CC</sub> OE 1 V<sub>CC</sub> GND GND VCC OE 1 VCC 42 41 40 39 42 41 40 39 B0+ GND 38 A0+ 38 **GND** 2 37 B0-2 37 A0+ A0-B0+ 3 A0-36 B1+ C0+ 3 36 B0-B1-GND 4 35 C0-35 GND 4 C0+  $V_{CC}$ 5 34 A1+ 5 34 Vcc **B1**+ A1+ 6 33 C0-A1-6 33 7 C1+ A1-32 C1+ 7 32 B1-V<sub>CC</sub> 8 C1-8 31 C1-31 Vcc SEL 9 SEL 30 Vcc  $V_{CC}$ 9 30 GND 10 29 B2+ A2+ 10 29 GND A2+ 11 B2-A2- 11 28 **B2**+ 28 A2- 12 27 B3+ C2+ 12 27 B2-В3-V<sub>CC</sub> 13 26 C2- 13 26 Vcc **GND** 14 25 25 **GND** C2+ A3+ 14 A3+ 15 24 C2-A3- 15 24 B3+ A3- 16 23 C3+ C3+ 16 23 B3-**GND** 17 C3- 17 22 C3-22 **GND** 19 20 20 V<sub>CC</sub> OE 2 V<sub>CC</sub> GND GND VCC OE 2 VCC



# 7. Block Diagram



## 8. Principle of Operation

## 8.1. Truth Table

Inputs OE1	Inputs OE2	Inputs SEL	Function	
L	_	L	An+ port = Bn+ port, An- port = Bn- port	(n=0,1)
L	_	Н	An+ port = Cn+ port, An- port = Cn- port	(n=0,1)
Н	_	_	An, Bn, Cn port Disconnect	(n=0,1)
_	L	L	An+ port = Bn+ port, An- port = Bn- port	(n=2,3)
_	L	Н	An+ port = Cn+ port, An- port = Cn- port	(n=2,3)
_	Н	_	An, Bn, Cn port Disconnect	(n=2,3)

—: Don't care.



## 9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	$V_{CC}$		-0.5 to 4.6	V
Input voltage (OE1, OE2, SEL)	V <sub>IN</sub>		-0.5 to 4.6	V
Switch I/O voltage	$V_S$		-0.5 to V <sub>CC</sub> +0.5	V
Switch I/O current	I <sub>S</sub>		50	mA
Power dissipation	$P_{D}$		500	mW
V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>		±50	mA
Storage temperature	T <sub>stg</sub>		-55 to 125	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### 10. Operating Ranges (Note)

Characteristics	Symbol Note		Rating	Unit
Supply voltage	V <sub>CC</sub>		3.0 to 3.6	V
Input voltage (OE1, OE2, SEL)	V <sub>IN</sub>		0 to 3.6	V
Switch I/O voltage	V <sub>S</sub>		0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>		-40 to 85	°C
Input rise time	dt/dv		0 to 10	ns/V
Input fall time	dt/dv		0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused control inputs must be tied to either  $V_{CC}$  or GND.

#### 11. Electrical Characteristics

# 11.1. DC Characteristics (Note) (Unless otherwise specified, Ta = -40 to 85 °C)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage (OE1, OE2, SEL)	V <sub>IH</sub>		_	3.0 to 3.6	0.65 × V <sub>CC</sub>	_	_	V
Low-level input voltage (OE1, OE2, SEL)	V <sub>IL</sub>		_	3.0 to 3.6			0.35 × V <sub>CC</sub>	V
Input leakage current (OE1, OE2, SEL)	I <sub>IN</sub>		V <sub>IN</sub> = 0 to 3.6 V	3.0 to 3.6			±1	μА
Switch OFF-state leakage current	I <sub>SZ</sub>		$V_{IS} = 0$ to $V_{CC}$ , $\overline{OE}1 = \overline{OE}2 = V_{CC}$	3.0 to 3.6		_	±1	μА
ON-resistance	R <sub>ON</sub>	(Note 1)	$V_{IS} = 0 \text{ V}, I_{IS} = 30 \text{ mA}$	3.0		7.5	11.5	Ω
	R <sub>ON</sub>	(Note 1)	V <sub>IS</sub> = 1.2 V, I <sub>IS</sub> = 30 mA	3.0	_	8.5	13.5	Ω
Difference of ON-resistance between switches (bit to bit)	ΔR <sub>ON</sub>	(Note 1)	V <sub>IS</sub> = 0 V, 1.2 V, I <sub>IS</sub> = 15 mA	3.0		0.1	_	Ω
ON-resistance flatness	R <sub>ON(flat)</sub>	(Note 1)	$V_{IS}$ = 0 V to 1.2 V, $I_{IS}$ = 15 mA	3.0	_	1	_	Ω
Quiescent supply current	I <sub>CC</sub>		$\frac{V_{IN}}{OE1} = V_{CC}$ or GND, $OE1 = OE2 = V_{CC}$	3.6		_	1	μА
Quiescent supply current	I <sub>CC</sub>		$\frac{V_{IN}}{OE1} = V_{CC}$ or GND, OE1 = OE2 = GND	3.6	_	400	800	μА

Note : All typical values are at  $T_a = 25$  °C.

Note 1: ON-resistance is measured by measuring the voltage drop across the switch at the indicated current.



# 11.2. AC Characteristics (Note) (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
Propagation delay time	t <sub>PLH</sub> / t <sub>PHL</sub>	(Note 1)	$C_L = 5 \text{ pF}$ See Fig. 12.1	$3.3\pm0.3$	_	0.1	_	ns
Turn-ON time (SEL to Output)	t <sub>on</sub>		$R_L$ = 50 $\Omega$ , $C_L$ = 5 pF See Fig. 12.2	$3.3\pm0.3$		10	15	ns
Turn-ON time (OE to Output)	t <sub>on</sub>		$R_L$ = 50 $\Omega$ , $C_L$ = 5 pF See Fig. 12.2	$3.3\pm0.3$		37	50	μS
Turn-OFF time (SEL to Output)	t <sub>off</sub>		$R_L$ = 50 $\Omega$ , $C_L$ = 5 pF See Fig. 12.2	$3.3\pm0.3$		3.5	5	ns
Turn-OFF time (OE to Output)	t <sub>off</sub>		$R_L$ = 50 $\Omega$ , $C_L$ = 5 pF See Fig. 12.2	$3.3\pm0.3$		5	6.5	ns
Break before make	TBBM		$R_L$ = 50 $\Omega$ , $C_L$ = 5 pF See Fig. 12.3	$3.3\pm0.3$	3	_	9	ns
Output skew (bit to bit)	t <sub>SK(b)</sub>	(Note 1)	$C_L$ = 5 pF See Fig. 12.4	$3.3\pm0.3$		5	_	ps
Output skew (channel to channel)	t <sub>SK(CH)</sub>	(Note 1)	$C_L$ = 5 pF See Fig. 12.5	$3.3\pm0.3$		10	_	ps
Differential OFF isolation	DDOIRR	(Note 1)	$R_T$ = 50 $\Omega$ , f = 4 GHz See Fig. 12.6	$3.3\pm0.3$	_	-20	_	dB
Differential Near-end crosstalk	DDNEXT	(Note 1)	$R_T$ = 50 $\Omega$ , f = 4 GHz See Fig. 12.7	$3.3\pm0.3$	_	-40	_	dB
Differential return loss	DDRL	(Note 1)	$R_T$ = 50 $\Omega$ , f = 4 GHz See Fig. 12.8	$3.3\pm0.3$	_	-20	_	dB
Differential insertion loss	DDIL	(Note 1)	$R_T$ = 50 $\Omega$ , f = 4 GHz See Fig. 12.8	$3.3\pm0.3$	_	-1	_	dB
-3dB Bandwidth	BW	(Note 1)	$R_T$ = 50 $\Omega$ , $C_L$ = 0 pF See Fig. 12.8	$3.3\pm0.3$		10	_	GHz

Note : All typical values are at  $T_a = 25$  °C.

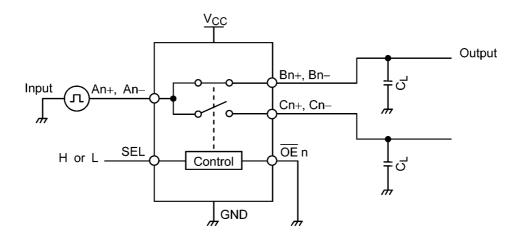
Note 1: This parameter is guaranteed by design.

# 11.3. Capacitive Characteristics (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Input capacitance (OE1, OE2, SEL)	C <sub>IN</sub>		V <sub>IN</sub> = 0 V	3.3	3	pF
Switch terminal OFF-capacitance (An+, An-)	C <sub>I/O</sub>		$\overline{OE}1 = \overline{OE}2 = V_{CC}, V_{IS} = 0 V$	3.3	0.8	pF
Switch terminal OFF-capacitance (Bn+, Bn-, Cn+, Cn-)			$\overline{OE}1 = \overline{OE}2 = V_{CC}, V_{IS} = 0 V$	3.3	0.5	pF
Switch terminal ON-capacitance	C <sub>I/O</sub>		$\overline{OE}1 = \overline{OE}2 = GND, V_{IS} = 0 V$	3.3	1.5	pF

Note: Parameter guaranteed by design.

## 12. AC Electrical Test Circuit (Fig)



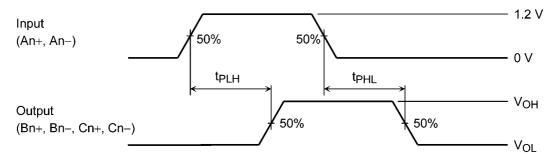
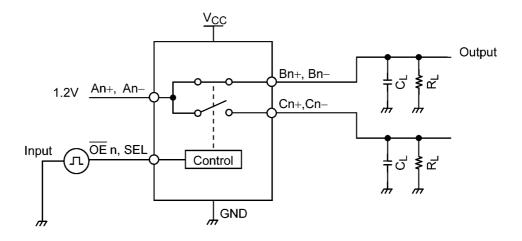


Fig. 12.1 Propagation delay time



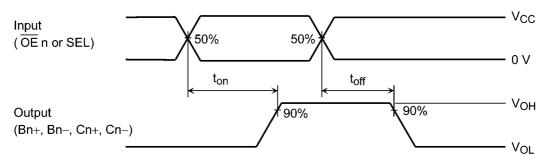


Fig. 12.2 Turn-ON and Turn-OFF time

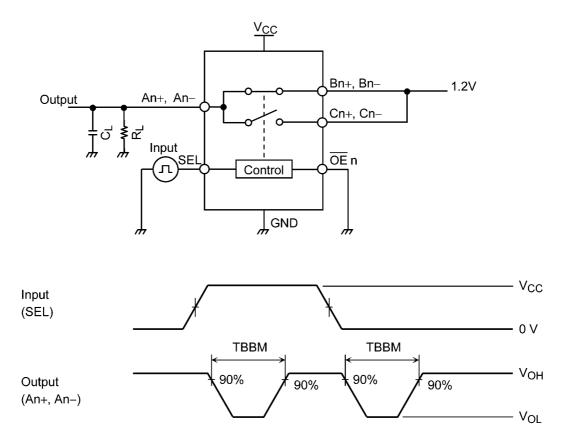
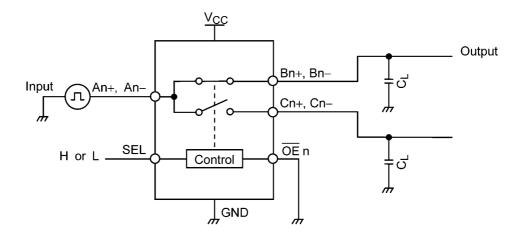


Fig. 12.3 Break before make



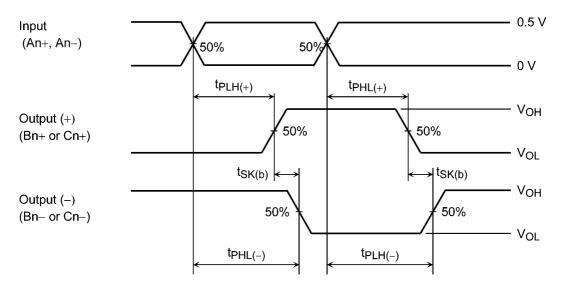


Fig. 12.4 Output skew (bit to bit)

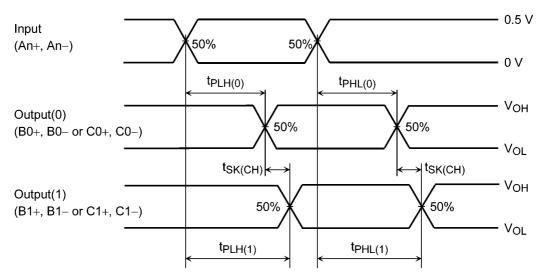


Fig. 12.5 Output skew (channel to channel)

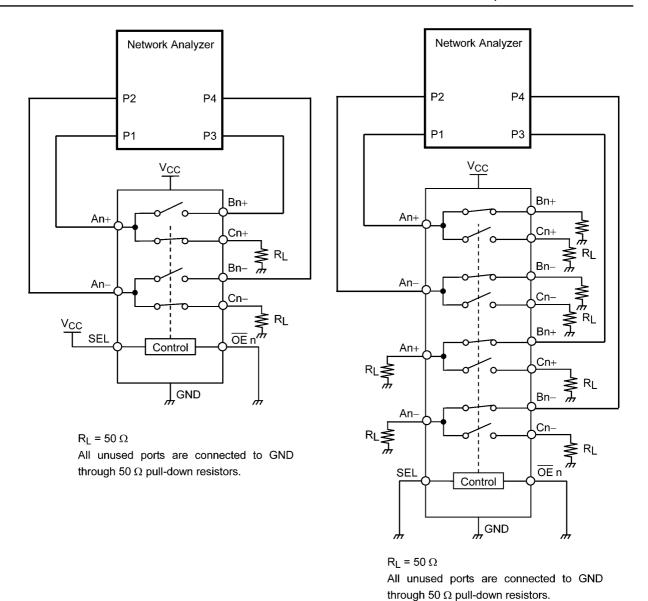
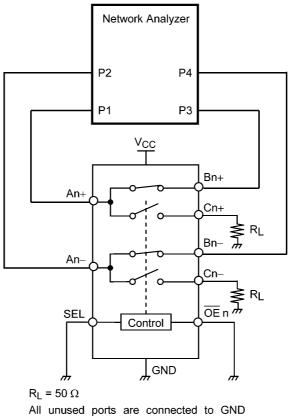


Fig. 12.6 Differential OFF isolation

Fig. 12.7 Differential Near-end crosstalk



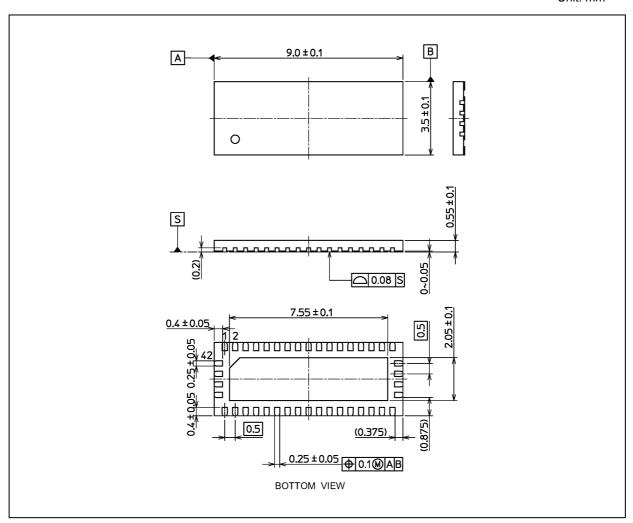
All unused ports are connected to GNE through 50  $\Omega$  pull-down resistors.

Fig. 12.8 Differential return loss, Differential insertion loss, -3dB Bandwidth



# **Package Dimensions**

Unit: mm



Weight: 0.06 g (typ.)

Package Name(s)
TOSHIBA: P-UQFN42-0409-0.50-001
Nickname: TQFN42



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